

## AUTHOR INDEX TO VOLUME 4

Agarwal, B.D., see P. Kumar 4 (1986) 111

Akhtar, D., see R.D.K. Misra 4 (1986) 207

Albaugh, K.B. and A.F. Puttlitz, Topographic effects on film thickness 4 (1986) 133

Albaugh, K.B., Irreversibility of anodic bonding 4 (1986) 465

Al-Chalabi, S.A.M., K.M. Barfoot and B.L. Weiss, Titanium incorporation into  $\text{LiNbO}_3$ , using scanned electron beam annealing 4 (1986) 93

Aljishi, S., see V.N. Kalema 4 (1986) 320

Alonso, J.A. and J.M. López, Glass-forming ability in binary alloys produced by ion beam mixing and by laser quenching 4 (1986) 316

Ance, C., see N.M. Ravindra 4 (1986) 343

Angelucci, R., G. Lulli and P.G. Merli, e-beam-induced lateral seeded epitaxy of silicon on insulator 4 (1986) 185

Antonini, M., see M. Sacchi 4 (1985) 10

Armor, J.N., E.J. Carlson and G. Carrasquillo, Metallic aerogels: a novel synthesis of very fine copper powder 4 (1986) 373

Bagley, B.G., W.E. Quinn, C.J. Mogab and M.J. Vasile, The effect of reactor configuration on the oxygen plasma conversion of an organosilicon to  $\text{SiO}_2$  4 (1986) 154

Balkanski, M., see C. Julien 4 (1986) 401

Banerjee, K. and V.A. Singh, Impurity density of states of the oxygen thermal donor in silicon. Formalism and application 4 (1986) 447

Barfoot, K.M., see S.A.M. Al-Chalabi 4 (1986) 93

Basu, P.K., see S. Biswas 4 (1986) 81

Bensahel, D., see M. Haond 4 (1985) 13

Besse, J.P., see A. Jorio 4 (1986) 386

Bhaduri, S.B., Brittleness estimation of ceramic particulate composites 4 (1986) 211

Bhattacharya, R.S., C.N. Raffoul and A.K. Rai, Corrosion behavior of rf-sputtered  $\text{Ni}_{45}\text{Cr}_{55}$  film 4 (1986) 271

Bicknell, R.W., see G.J. Rees 4 (1986) 455

Biswas, S., P. Pramanik and P.K. Basu, A solution growth technique for the preparation of zinc sulfide thin film 4 (1986) 81

Bonner, W.A., see A.T. Macrander 4 (1986) 181

Buckley, S.N., see M. Sacchi 4 (1985) 10

Buddhudu, S., see V. Ramesh Babu 4 (1986) 99

Buddhudu, S., see Ch. Gopinath 4 (1986) 279

Buddhudu, S., see V. Ramesh Babu 4 (1986) 389

Buddhudu, S., see V. Ramesh Babu 4 (1986) 495

Caillet, M., A. Galerie and M. Pons, Influence of laser surface boronizing on the high-temperature oxidation of nickel 4 (1986) 102

Cao, W.W., see Y. Sun 4 (1986) 329

Carlson, E.J., see J.N. Armor 4 (1986) 373

Carrasco, B., see C.E. Infante	4 (1986) 194
Carrasquillo, G., see J.N. Armor	4 (1986) 373
Castaing, J., see J.L. Routbort	4 (1986) 149
Chai, P., see Y. Li	4 (1986) 117
Chan, A.Y.C., Some application-orientated properties of xerographic copper phthalocyanine-acrylate films	4 (1986) 239
Chaudhary, R.N.P., see A.K. Pradhan	4 (1986) 223
Chen, H., G.E. White and S.R. Stock, Measurement of thermal stress in $Pd_2Si$ film on Si(111) by absorption edge contour mapping	4 (1986) 61
Chen, H., Observation of Pendellösung fringes in reflection-section topographs of bent silicon crystals	4 (1986) 65
Chen, Z., see H. Shi	4 (1986) 290
Chou, T.C. and Y.T. Chou, Up-hill diffusion of hafnium in $Ni_3Al$ intermetallic alloys	4 (1986) 423
Chou, Y.T., see T.C. Chou	4 (1986) 423
Chuah, D.G.S. and H.K. Fun, A study of tin oxide film by vacuum evaporation	4 (1986) 274
Chung, D.D.L., see R.V. Prasad	4 (1986) 71
Conde, A., see H. Miranda	4 (1986) 226
Conde, A., see H. Miranda	4 (1986) 442
Conde, C., see H. Miranda	4 (1986) 226
Conde, C.F., see H. Miranda	4 (1986) 442
Condrate Sr., R.A., see C.V. Edney	4 (1986) 470
Conejo, J.M., N. de la Rosa-Fox, L. Esquivias and R. Jiménez-Garay, Tetrahedral bonding in the glassy semiconductor $Cu_{15}As_{34}Se_{51}$	4 (1986) 481
Constant, G., see F. Maury	4 (1986) 249
Crandall, W.B., see C.V. Edney	4 (1986) 470
Cross, L.E., see Y. Sun	4 (1986) 329
Cross, L.E., see P. Sliva	4 (1986) 409
Cross, L.E., see D. Damjanovic	4 (1986) 414
Cross, L.E., see P. Sliva	4 (1986) 475
Cembrera, F.L., see A. Muñoz	4 (1986) 490
Damjanovic, D., T.R. Gururaja, S.J. Jang and L.E. Cross, Temperature behavior of the complex piezoelectric $d_{31}$ coefficient in modified lead titanate ceramics	4 (1986) 414
Danno, M. and M. Hanabusa, Amorphous carbon films prepared by photo-CVD from acetylene	4 (1986) 261
Dasgupta, D., see M.K. Karanjai	4 (1986) 368
Dawson, R.M.A., see V.N. Kalema	4 (1986) 320
Dean, B.E., see S. McDevitt	4 (1986) 451
Dean, R.E., see G. Smolinsky	4 (1986) 256
Dechelle, F., see N.M. Ravindra	4 (1986) 343
De la Rosa-Fox, N., see J.M. Conejo	4 (1986) 481
De Roy, M.E., see A. Jorio	4 (1986) 386
Derrey, T., J.M. Saiter and C. Vautier, Photodarkening of amorphous $Se_{100-x}Ge_x$ alloys ( $2 < x < 16$ )	4 (1986) 365
Devashrayee, N.M., see R.K. Nahar	4 (1986) 265
DiSalvo, F.J., see L.F. Schneemeyer	4 (1986) 121
Dobrilla, P., A vapor-phase hydroxide dislocation etch for GaAs	4 (1985) 17
Dorman, H.H., see N.B. Singh	4 (1986) 357
Dutartre, D., see M. Haond	4 (1985) 13

Ebothé, J., Effects of back interface impurities on the action spectrum of thin cadmium sulfide layers	4 (1986) 85
Edney, C.V., R.A. Condrate Sr., W.B. Crandall and M.E. Washburn, A spectral investigation of $Y_2O_3$ - $Al_2O_3$ materials prepared by a sol-gel process	4 (1986) 470
El Chazly, N.M., Formability of 3004, H-19 alloy for rigid containers	4 (1986) 159
El-Masry, N.A., see P.L. Jones	4 (1986) 381
Esquivias, L., see J.M. Conejo	4 (1986) 481
Fathy, D., see N.M. Ravindra	4 (1986) 337
Fathy, D., see D. Lu	4 (1986) 461
Feichtner, J.D., see N.B. Singh	4 (1985) 21
Fekade, K., see G.L. Harris	4 (1986) 77
Felton, G.J., see G.L. Harris	4 (1986) 77
Feng, J., see S. Wen	4 (1986) 420
Ferraton, J.P., see N.M. Ravindra	4 (1986) 343
Fleury, G., see J.M. Saiter	4 (1986) 178
Fournier, C. and S. Mil'shtein, Fine polishing of polycrystalline GaAs	4 (1986) 294
Fujii, T., M. Nakajima and T. Fukuda, Growth of Si and In double-doped dislocation-free conductive GaAs crystal by the LEC technique	4 (1986) 189
Fujimura, N., see T. Ito	4 (1986) 350
Fukuda, T., see T. Fujii	4 (1986) 189
Fun, H.K., see D.G.S. Chuah	4 (1986) 274
Gaida, W.E., see N.B. Singh	4 (1985) 21
Galerie, A., see M. Caillet	4 (1986) 102
Gallagher, P.K., see E.M. Vogel	4 (1985) 5
Garg, A., see P. Kumar	4 (1986) 111
Garg, A. and T.R. McNelley, Estimation of martensite carbon content in as-quenched AISI 52100 steel by X-ray diffraction	4 (1986) 214
Gaw, C.A., see C.L. Reynolds Jr.	4 (1986) 439
Georgson, M., see A. Roos	4 (1986) 49
Gerberich, W.W., see M. Kaczorowski	4 (1986) 244
Gopinath, Ch., L. Rama Moorthy and S. Buddhudu, Spectrum of Nd(III):1,10-phenanthroline	4 (1986) 279
Goretta, K.C., see J.L. Routbort	4 (1986) 149
Goslawsky, H., K.-D. Husemann, J. Luck, W.W. Szacki and H.J. Lewerenz, Impurity scavenging by foreign phase in heterogeneous CuInS <sub>2</sub>	4 (1986) 198
Gururaja, T.R., see P. Sliva	4 (1986) 409
Gururaja, T.R., see D. Damjanovic	4 (1986) 414
Gururaja, T.R., see P. Sliva	4 (1986) 475
Hanabusa, M., see M. Danno	4 (1986) 261
Haond, M., D. Dutartre and D. Bensahel, Improved heat-sink structure providing single-crystal SOI films prepared by lamp zone melting	4 (1985) 13
Harris, D.C. and R.W. Schwartz, HgTe films from photolysis of (t-butyl)HgTe(t-butyl)	4 (1986) 370
Harris, G.L., K.H. Jackson, G.J. Felton, K.R. Osborne, K. Fekade and M.G. Spencer, Low-pressure growth of single-crystal silicon carbide	4 (1986) 77
Hatzikraniotis, E., see C. Julien	4 (1986) 401

Hirvonen, J.-P. and J.W. Mayer, Fretting wear of nitrogen-implanted AISI 304 stain-	
less steel	4 (1986) 404
Hockly, M., see P.C. Spurdens	4 (1986) 353
Hopkins, R.H., see N.B. Singh	4 (1985) 21
Hopkins, R.H., see N.B. Singh	4 (1986) 357
Houser, C.A. and W.B. White, Effect of fluid flow on the hydration of a	
sodium-calcium-silicate glass	4 (1986) 397
Husemann, K.-D., see H. Goslawsky	4 (1986) 198
Infante, C.E. and B. Carrasco, Stoichiometry and oxygen structure of Fe sillenite	4 (1986) 194
Irene, E.A., see N.M. Ravindra	4 (1986) 337
Ito, T., N. Fujimura and Y. Nakayama, Reactions between Ti and Al films on a-Si:H	4 (1986) 350
Jacco, J.C., see G.M. Loiacono	4 (1985) 27
Jackson, K.H., see G.L. Harris	4 (1986) 77
Jang, S.J., see D. Damjanovic	4 (1986) 414
Jankowski, A.F. and J.F. Shewbridge, Grain size dependence on layer thickness in	
composition modulated thin films	4 (1986) 313
Jiang, Y., see H. Shi	4 (1986) 290
Jiménez-Garay, R., see E. Márquez	4 (1986) 52
Jiménez-Garay, R., see J. Vázquez	4 (1986) 171
Jiménez-Garay, R., see J. Vázquez	4 (1986) 360
Jiménez-Garay, R., see J.M. Conejo	4 (1986) 481
Jiménez-Garay, R., see J. Vázquez	4 (1986) 485
Johansen, A., see E. Johnson	4 (1985) 33
Johnson, E., A. Johansen and L. Sarholt-Kristensen, Formation of ordered Al <sub>3</sub> Li by	
ion implantation of lithium into aluminium	4 (1985) 33
Jones, P.L., J.H. Lind, N.A. El-Masry, H.H. Stadelmaier and F. Rothwarf, A positron	
annihilation study of an Fe <sub>14</sub> Nd <sub>2</sub> B-type permanent magnet alloy	4 (1986) 381
Jorio, A., M.E. de Roy and J.P. Besse, Preparation of V <sub>6</sub> O <sub>13</sub> electrodes by electrolytic	
reduction of molten salts	4 (1986) 386
Julien, C., E. Hatzikraniotis and M. Balkanski, Electrical properties of lithium inter-	
calated p-type GaSe	4 (1986) 401
Kaczorowski, M. and W.W. Gerberich, The "effective" penetration depth of back-	
scattered electrons associated with electron channeling patterns (ECPs)	4 (1986) 244
Kalema, V.N., S. Aljishi, R.M.A. Dawson, D. Slobodin and S. Wagner, The dielectric	
constants of a-Si,Ge:H,F alloys	4 (1986) 320
Kamegashira, N. and S. Umeno, Transition temperature of BaEu <sub>2</sub> Mn <sub>2</sub> O <sub>7</sub>	4 (1986) 236
Kapale, V.G., see S.M. Patel	4 (1986) 145
Karanjai, M.K. and D. Dasgupta, Cadmium sulphide thin films by the dip technique	4 (1986) 368
Kawasaki, H., see H. Yoshimatsu	4 (1986) 426
Kissinger, W., see H. Neumann	4 (1986) 57
Kitai, A.H., M.J. Skvarla and G.J. Wolga, Single crystal ZnS:Mn prepared by ion	
implantation	4 (1985) 30
Komarneni, S. and R. Roy, Anomalous microwave melting of zeolites	4 (1986) 107
Kremer, R.E., see M.R. Tamjidi	4 (1986) 90

Kulkarni, R.G. and R.V. Upadhyay, High-temperature Mössbauer study of the Cu-Cd ferrite system	4 (1986) 168
Kumar, P., A. Garg and B.D. Agarwal, Dynamic compressive behaviour of unidirectional GFRP for various fibre orientations	4 (1986) 111
Lakshman, S.V.J. and L. Rama Moorthy, Luminescent branching ratios and radiative lifetimes of $Tm^{3+}$ in $POCl_3 : SnCl_4$ laser liquid	4 (1985) 39
Lakshman, S.V.J., see A. Sundar Jacob	4 (1985) 45
Lemmon, D.H., see N.B. Singh	4 (1985) 21
Lewerenz, H.J., see H. Goslowsky	4 (1986) 198
Lhymn, C. and J.M. Schultz, Microscopy of electrical treeing behavior	4 (1986) 433
Li, Y., J. Shen, P. Chai and Q. Wang, A new method for selecting the IR oxygen- and carbon-free reference sample	4 (1986) 117
Liedl, G.L., see H. Sato	4 (1986) 136
Lind, J.H., see P.L. Jones	4 (1986) 381
Liu, N.C., see H.H. Stadelmaier	4 (1986) 304
Liu, N.C. and H.H. Stadelmaier, High coercivity permanent magnet materials based on iron-rare-earth-carbon alloys	4 (1986) 377
Loiacono, G.M. and J.C. Jacco, Thermal characterization of $KClO_3$ , $KBrO_3$ , and $KIO_3$	4 (1985) 27
López, J.M., see J.A. Alonso	4 (1986) 316
Lu, D., J.J. Wortman and D. Fathy, Bonding silicon wafers by use of electrostatic fields followed by rapid thermal heating	4 (1986) 461
Luck, J., see H. Goslowsky	4 (1986) 198
Lulli, G., see R. Angelucci	4 (1986) 185
Macrander, A.T., W.A. Bonner and E.M. Monberg, An evaluation of (100) sulfur doped InP for use as a first crystal in an X-ray double-crystal diffractometer	4 (1986) 181
Mahajan, S., see S. McDevitt	4 (1986) 451
Manara, A., see M. Sacchi	4 (1985) 10
Mansour, S., see H. Sato	4 (1986) 136
Márquez, E., P. Villares and R. Jiménez-Garay, Pre-switching non-linear region and delay time in the $Cu_{0.15}As_{0.35}Se_{0.50}$ semiconducting glass	4 (1986) 52
Márquez, E., see J. Vázquez	4 (1986) 360
Márquez, R., see H. Miranda	4 (1986) 226
Márquez, R., see H. Miranda	4 (1986) 442
Marquez, R., see A. Muñoz	4 (1986) 490
Martins, R.B. and C.A. Ribeiro, Direct observation of the influence of inhomogeneities in InP substrates on the quality of quaternary layers	4 (1986) 458
Masumoto, K., see K. Mochizuki	4 (1986) 298
Masumoto, K., see K. Mochizuki	4 (1986) 301
Matson, D.W., R.C. Petersen and R.D. Smith, The preparation of polycarbosilane powders and fibers during rapid expansion of supercritical fluid solutions	4 (1986) 429
Maury, F. and G. Constant, Structural characterizations of MOCVD $(GaAs)_{1-x}(SiC_2:H)_x$ films: evidence for a multiphase structure	4 (1986) 249
Mayer, J.W., see J.-P. Hirvonen	4 (1986) 404
Mazelsky, R., see N.B. Singh	4 (1985) 21
Mazelsky, R., see N.B. Singh	4 (1986) 357
McDevitt, S., B.E. Dean, D.G. Ryding, F.J. Scheltens and S. Mahajan, Characterization of CdTe and (Cd,Zn)Te single-crystal substrates	4 (1986) 451

McNelley, T.R., see A. Garg 4 (1986) 214

Merli, P.G., see R. Angelucci 4 (1986) 185

Mil'shtein, S., see C. Fournier 4 (1986) 294

Miranda, H., C. Conde, A. Conde and R. Márquez, Crystallization kinetics of  $Fe_{79}B_{13}Si_8$  metallic glass 4 (1986) 226

Miranda, H., C.F. Conde, A. Conde and R. Márquez, On the crystallization of  $Fe_{77}B_{16}Si_5Cr_2$  alloy 4 (1986) 442

Misra, A.K., Effect of electric potentials on solidification of near eutectic Pb-Sb-Sn alloy 4 (1986) 176

Misra, R.D.K. and D. Akhtar, Effect of charging parameters on hydrogen embrittlement behaviour of  $Ni_{60}Nb_{35}Cr_5$  glass 4 (1986) 207

Mochizuki, K. and K. Masumoto, Growth of CdTe single crystals by THM (travelling heater method) and its repetition effect 4 (1986) 298

Mochizuki, K. and K. Masumoto, *I-V* characteristics of CdTe single crystals 4 (1986) 301

Mogab, C.J., see B.G. Bagley 4 (1986) 154

Monberg, E.M., see A.T. Macrander 4 (1986) 181

Munibhadraiah, B., see B.C. Venkata Reddy 4 (1986) 219

Muñoz, A., F.L. Cumbre and R. Marquez, The use of Lanczos's discriminative window in deconvolution of amorphous patterns: a useful variant of the Mencik method 4 (1986) 490

Nahar, R.K. and N.M. Devashrayee, Microstructure and properties of AlSi-Ti multi-layer structure 4 (1986) 265

Nakajima, M., see T. Fujii 4 (1986) 189

Nakayama, Y., see T. Ito 4 (1986) 350

Narayan, J., see N.M. Ravindra 4 (1986) 337

Narayan, J., see N.M. Ravindra 4 (1986) 343

Neumann, H., W. Kissinger and R.D. Tomlinson, Intervalence-band absorption spectra and hole effective masses in  $CuGaTe_2$  4 (1986) 57

Nygren, S.F., see C.L. Reynolds Jr. 4 (1986) 439

Osaka, A., see H. Yoshimatsu 4 (1986) 426

Osborne, K.R., see G.L. Harris 4 (1986) 77

Otsuka, N., see H. Sato 4 (1986) 136

Paesler, M.A., see C.Y. Yang 4 (1986) 233

Pan, X., M.W. Ruckman, C. Zhang and M. Strongin, Observation of novel Ni/Nb and Ni/Ta surface compounds produced by heat treatment 4 (1986) 125

Patel, S.M. and V.G. Kapale, Electrical properties of  $AgGaSe_2$  films 4 (1986) 145

Petersen, R.C., see D.W. Matson 4 (1986) 429

Pons, M., see M. Caillet 4 (1986) 102

Poole, J.E., see C.E. Wickersham Jr. 4 (1986) 268

Pradhan, A.K., R.N.P. Chaudhary and W. Wendl, Raman and infrared spectra of  $SmAsO_4$  4 (1986) 223

Pramanik, P., see S. Biswas 4 (1986) 81

Prasad, P.R. and U.S. Shricastava, On the stability of the solid-liquid interface during solidification under convection 4 (1985) 19

Prasad, R.V., F.A. Selim and D.D.L. Chung, Semi-insulating polysilicon: growth, processing and structural characterization	4 (1986) 71
Puttlitz, A.F., see K.B. Albaugh	4 (1986) 133
Quinn, W.E., see B.G. Bagley	4 (1986) 154
Raffoul, C.N., see R.S. Bhattacharya	4 (1986) 271
Rai, A.K., see R.S. Bhattacharya	4 (1986) 271
Rama Moorthy, L., see S.V.J. Lakshman	4 (1985) 39
Rama Moorthy, L., see V. Ramesh Babu	4 (1986) 99
Rama Moorthy, L., see Ch. Gopinath	4 (1986) 279
Ramesh Babu, V., L. Rama Moorthy and S. Buddhudu, Absorption spectrum of $\text{Nd}^{3+}:\text{LiNH}_4\text{SO}_4$ single crystals	4 (1986) 99
Ramesh Babu, V. and S. Buddhudu, A comparative study of spectral energies and oscillator strengths of $\text{PrCl}_3$ organic complexes	4 (1986) 389
Ramesh Babu, V. and S. Buddhudu, Absorption spectra of $\text{NdCl}_3$ complexes in alcohols	4 (1986) 495
Ravindra, N.M., D. Fathy, J. Narayan, J.K. Srivastava and E.A. Irene, Two-step oxidation processes in silicon	4 (1986) 337
Ravindra, N.M., J. Narayan, C. Ance, F. Dechelle and J.P. Ferraton, Low-temperature optical properties of hydrogenated amorphous silicon	4 (1986) 343
Rees, G.J., D.J. Stirland and R.W. Bicknell, A simple technique to evaluate the density of overlapping etch pits in GaAs	4 (1986) 455
Ren, Y., see H. Shi	4 (1986) 290
Reynolds Jr., C.L., S.F. Nygren and C.A. Gaw, Mg doping in LPE grown AlGaAs and the temperature dependence of threshold current in injection lasers	4 (1986) 439
Ribeiro, C.A., see R.B. Martins	4 (1986) 458
Riemer, E.K. and T.G. Stoebe, Photoluminescence in the band crossover region of $\text{Al}_x\text{Ga}_{1-x}\text{As}$	4 (1986) 229
Roos, A. and M. Georgson, Optical properties of tin oxide on anodized aluminium	4 (1986) 49
Rothwarf, F., see P.L. Jones	4 (1986) 381
Routbort, J.L., K.C. Goretta and J. Castaing, Effect of $\text{CO}_2/\text{CO}$ atmospheres on high-temperature deformation of MnO single crystals	4 (1986) 149
Roy, D.M., see R. Roy	4 (1986) 323
Roy, R., see S. Komarneni	4 (1986) 107
Roy, R., R.A. Roy and D.M. Roy, Alternative perspectives on "quasi-crystallinity": non-uniformity and nanocomposites	4 (1986) 323
Roy, R.A., see R. Roy	4 (1986) 323
Ruckman, M.W., see X. Pan	4 (1986) 125
Ryding, D.G., see S. McDevitt	4 (1986) 451
Sacchi, M., M. Antonini, S.N. Buckley and A. Manara, Alkali effects on bubble formation in irradiated borosilicate glasses	4 (1985) 10
Saiter, J.M., G. Fleury, C. Viger and C. Vautier, Activation energy of conductivity in amorphous Bi-Se alloys	4 (1986) 178
Saiter, J.M., see T. Derrey	4 (1986) 365
Sarholt-Kristensen, L., see E. Johnson	4 (1985) 33
Sato, H., N. Otsuka, G.L. Liedl and S. Mansour, Formation of elongated Particles in $\beta$ -SiC compacts	4 (1986) 136

Sayers, D.E., see C.Y. Yang	4 (1986) 233
Scheetz, B.E., see P. Sliva	4 (1986) 409
Scheetz, B.E., see P. Sliva	4 (1986) 475
Scheltens, F.J., see S. McDevitt	4 (1986) 451
Schneemeyer, L.F., S.E. Spengler, J.V. Waszczak and F.J. DiSalvo, New transition metal substituted cadmium tellurides	4 (1986) 121
Schultz, J.M., see C. Lhymn	4 (1986) 433
Schwartz, R.W., see D.C. Harris	4 (1986) 370
Selim, F.A., see R.V. Prasad	4 (1986) 71
Shaw, W.J.D., Microsuperplastic behavior	4 (1985) 1
Shen, J., see Y. Li	4 (1986) 117
Shewbridge, J.F., see A.F. Jankowski	4 (1986) 313
Shi, H., H. Yu, Y. Ren, Y. Zou (Y. Chou), Z. Chen and Y. Jiang, Effect of baking on space-charge scattering in undoped n-type LPE GaAs	4 (1986) 290
Shricastava, U.S., see P.R. Prasad	4 (1985) 19
Singh, N.B., R.H. Hopkins, W.E. Gaida, D.H. Lemmon, J.D. Feichtner and R. Mazelsky, Growth and characterization of AgTlSe crystals	4 (1985) 21
Singh, N.B., R.H. Hopkins, R. Mazelsky and H.H. Dorman, Annealing experiments on silver gallium selenide crystals	4 (1986) 357
Singh, V.A., see K. Banerjee	4 (1986) 447
Skvarla, M.J., see A.H. Kitai	4 (1985) 30
Sliva, P., L.E. Cross, T.R. Gururaja and B.E. Scheetz, Macro-defect-free processing and low-frequency dielectric response of calcium aluminate cements	4 (1986) 409
Sliva, P., L.E. Cross, T.R. Gururaja and B.E. Scheetz, Relative dielectric permittivity of calcium aluminate cement-glass microsphere composites	4 (1986) 475
Slobodin, D., see V.N. Kalema	4 (1986) 320
Smith, R.D., see D.W. Matson	4 (1986) 429
Smolinsky, G. and R.E. Dean, LPCVD of silicon oxide films in the temperature range 410 to 600°C from diacetoxyditertiarybutoxysilane	4 (1986) 256
Spencer, M.G., see G.L. Harris	4 (1986) 77
Spengler, S.E., see L.F. Schneemeyer	4 (1986) 121
Spurdens, P.C. and M. Hockly, A TEM study of GaInAsP/InP heterojunctions grown by atmospheric pressure MOVPE	4 (1986) 353
Srivastava, J.K., see N.M. Ravindra	4 (1986) 337
Srivatsan, T.S., The influence of processing on the microstructure of an aluminum-lithium alloy	4 (1986) 201
Stadelmaier, H.H. and N.C. Liu, Effect of mechanical comminution on the intrinsic coercivity of Fe-Nd-B sintered magnets	4 (1986) 304
Stadelmaier, H.H., see N.C. Liu	4 (1986) 377
Stadelmaier, H.H., see P.L. Jones	4 (1986) 381
Stirland, D.J., see G.J. Rees	4 (1986) 455
Stock, S.R., see H. Chen	4 (1986) 61
Stoebe, T.G., see E.K. Riemer	4 (1986) 229
Strongin, M., see X. Pan	4 (1986) 125
Sun, Y., W.W. Cao and L.E. Cross, Electrostriction effect in glass	4 (1986) 329
Sundar Jacob, A. and S.V.J. Lakshman, Electronic spectra of $VO^{2+}$ in some Tutton salts	4 (1985) 45
Szacki, W.W., see H. Goslawsky	4 (1986) 198

Tamjidi, M.R. and R.E. Kremer, Composition gradients in Bridgman-grown $Hg_{1-x}Mn_xTe$	4 (1986) 90
Tanner, B.K., see S.N.M. Willcock	4 (1986) 307
Tomlinson, R.D., see H. Neumann	4 (1986) 57
Umeno, S., see N. Kamegashira	4 (1986) 236
Upadhyay, R.V., see R.G. Kulkarni	4 (1986) 168
Vasile, M.J., see B.G. Bagley	4 (1986) 154
Vautier, C., see J.M. Saiter	4 (1986) 178
Vautier, C., see T. Derrey	4 (1986) 365
Vázquez, J., P. Villares and R. Jiménez-Garay, A structural model of the amorphous alloy $As_{0.40}Se_{0.30}Te_{0.30}$ by random technique	4 (1986) 171
Vázquez, J., E. Márquez, P. Villares and R. Jiménez-Garay, Structural characteristics and some concepts related to switching properties in $As_{0.45}Se_{0.10}Te_{0.45}$ glassy alloy	4 (1986) 360
Vázquez, J., P. Villares and R. Jiménez-Garay, Analytical determination of the area below the first peak in the RDF for amorphous alloys	4 (1986) 485
Venkata Reddy, B.C. and B. Munibhadraiah, Electronic absorption spectrum of $Cu^{2+}$ ions doped in lithium caesium sulphate single crystal	4 (1986) 219
Viger, C., see J.M. Saiter	4 (1986) 178
Villares, P., see E. Márquez	4 (1986) 52
Villares, P., see J. Vázquez	4 (1986) 171
Villares, P., see J. Vázquez	4 (1986) 360
Villares, P., see J. Vázquez	4 (1986) 485
Vogel, E.M. and P.K. Gallagher, Thermoanalytical study of some fluoroberyllate glasses	4 (1985) 5
Wagner, S., see V.N. Kalema	4 (1986) 320
Wang, Q., see Y. Li	4 (1986) 117
Washburn, M.E., see C.V. Edney	4 (1986) 470
Waszczak, J.V., see L.F. Schneemeyer	4 (1986) 121
Weiss, B.L., see S.A.M. Al-Chalabi	4 (1986) 93
Wen, S. and J. Feng, Nanostructure defects in $Si_3N_4$	4 (1986) 420
Wendl, W., see A.K. Pradhan	4 (1986) 223
White, G.E., see H. Chen	4 (1986) 61
White, W.B., see C.A. Houser	4 (1986) 397
Wickersham Jr., C.E. and J.E. Poole, Explosive crystallization in gallium-doped amorphous germanium	4 (1986) 268
Willcock, S.N.M. and B.K. Tanner, The application of harmonic analysis to the magnetic properties of high-tensile steels	4 (1986) 307
Wolga, G.J., see A.H. Kitai	4 (1985) 30
Wortman, J.J., see D. Lu	4 (1986) 461
Yabuki, T., see H. Yoshimatsu	4 (1986) 426
Yang, C.Y., M.A. Paesler and D.E. Sayers, First crystallization of arsenic trisulfide from bulk glass: the synthesis of orpiment	4 (1986) 233
Yoshimatsu, H., A. Osaka, T. Yabuki and H. Kawasaki, Preparation of $ZrO_2 \cdot Al_2O_3$ composite powder by thermal decomposition of $Zr \cdot Al$ metallo-organic compound	4 (1986) 426
Yu, H., see H. Shi	4 (1986) 290

Zhang, C., see X. Pan 4 (1986) 125  
Zou, Y., see Z. Zou 4 (1986) 286  
Zou, Z. and Y. Zou, Identification of two bands in the PL spectra of SI LEC GaAs on  
the basis of a strain model 4 (1986) 286  
Zou, Y. (Chou, Y.), see H. Shi 4 (1986) 290

